

2N3019
2N3020

NPN SILICON TRANSISTOR



TO-39 CASE



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DESCRIPTION:

The CENTRAL SEMICONDUCTOR 2N3019, 2N3020 types are NPN silicon transistors designed for general purpose amplifier applications.

MARKING: FULL PART NUMBER

MAXIMUM RATINGS: ($T_A=25^\circ\text{C}$)

Collector-Base Voltage
Collector-Emitter Voltage
Emitter-Base Voltage
Continuous Collector Current
Power Dissipation
Power Dissipation ($T_C=25^\circ\text{C}$)
Operating and Storage Junction Temperature

SYMBOL

V_{CB0}	140
V_{CEO}	80
V_{EBO}	7.0
I_C	1.0
P_D	0.8
P_D	5.0
T_J, T_{stg}	-65 to +200

UNITS

V
V
V
A
W
W
$^\circ\text{C}$

ELECTRICAL CHARACTERISTICS: ($T_A=25^\circ\text{C}$ unless otherwise noted)

SYMBOL	TEST CONDITIONS	2N3019		2N3020		UNITS
		MIN	MAX	MIN	MAX	
I_{CBO}	$V_{CB}=90\text{V}$	-	10	-	10	nA
I_{CBO}	$V_{CB}=90\text{V}, T_A=150^\circ\text{C}$	-	10	-	10	μA
I_{EBO}	$V_{EB}=5.0\text{V}$	-	10	-	10	nA
BV_{CBO}	$I_C=100\mu\text{A}$	140	-	140	-	V
BV_{CEO}	$I_C=30\text{mA}$	80	-	80	-	V
BV_{EBO}	$I_E=100\mu\text{A}$	7.0	-	7.0	-	V
$V_{CE(SAT)}$	$I_C=150\text{mA}, I_B=15\text{mA}$	-	0.2	-	0.2	V
$V_{CE(SAT)}$	$I_C=500\text{mA}, I_B=50\text{mA}$	-	0.5	-	0.5	V
$V_{BE(SAT)}$	$I_C=150\text{mA}, I_B=15\text{mA}$	-	1.1	-	1.1	V
h_{FE}	$V_{CE}=10\text{V}, I_C=100\mu\text{A}$	50	-	30	100	
h_{FE}	$V_{CE}=10\text{V}, I_C=10\text{mA}$	90	-	40	120	
h_{FE}	$V_{CE}=10\text{V}, I_C=150\text{mA}$	100	300	40	120	
h_{FE}	$V_{CE}=10\text{V}, I_C=150\text{mA}, T_A=-55^\circ\text{C}$	40	-	-	-	
h_{FE}	$V_{CE}=10\text{V}, I_C=500\text{mA}$	50	-	30	100	
h_{FE}	$V_{CE}=10\text{V}, I_C=1.0\text{A}$	15	-	15	-	
f_T	$V_{CE}=10\text{V}, I_C=50\text{mA}, f=20\text{MHz}$	100	-	100	-	MHz
C_{ob}	$V_{CB}=10\text{V}, I_E=0, f=1.0\text{MHz}$	-	12	-	12	pF
C_{ib}	$V_{EB}=0.5\text{V}, I_C=0, f=1.0\text{MHz}$	-	60	-	60	pF
$r_b' C_C$	$V_{CE}=10\text{V}, I_C=10\text{mA}, f=4.0\text{MHz}$	-	400	-	400	ps
NF	$V_{CE}=10\text{V}, I_C=100\mu\text{A}, f=1.0\text{kHz}, R_S=1.0\text{k}\Omega$	-	4.0	-	-	dB

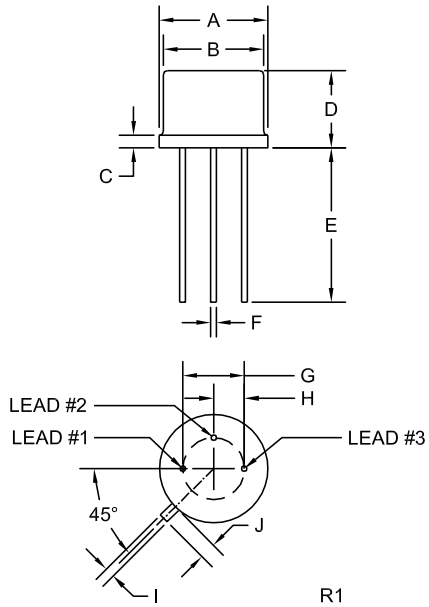
R1 (11-June 2012)

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TO-39 CASE - MECHANICAL OUTLINE



SYMBOL	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A (DIA)	0.335	0.370	8.51	9.40
B (DIA)	0.315	0.335	8.00	8.51
C	-	0.040	-	1.02
D	0.240	0.260	6.10	6.60
E	0.500	-	12.70	-
F (DIA)	0.016	0.021	0.41	0.53
G (DIA)	0.200		5.08	
H	0.100		2.54	
I	0.028	0.034	0.71	0.86
J	0.029	0.045	0.74	1.14

TO-39 (REV: R1)

LEAD CODE:

- 1) Emitter
- 2) Base
- 3) Collector

MARKING: FULL PART NUMBER

R1 (11-June 2012)

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